

isc Silicon NPN Power Transistor

2SD1684

DESCRIPTION

- •• Low Collector Saturation Voltage
 - : $V_{CE(sat)}$ = -0.5V(Max)@ I_C = -0.5A
- · Wide Area of Safe Operation
- Complement to Type 2SB1144
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



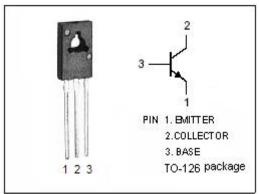
APPLICATIONS

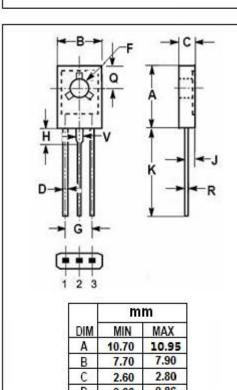
• Designed for 100V/1.5A Switching Applications



ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	120	V	
V _{CEO}	Collector-Emitter Voltage	100	V	
V _{EBO}	Emitter-Base Voltage	6	V	
Ic	Collector Current-Continuous	1.5	А	
I _{CP}	Collector Current-Pulse	2	А	
Pc	Collector Power Dissipation @ T_c =25 $^{\circ}$ C	10	W	
	Collector Power Dissipation @ Ta=25°C	1.5		
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	





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DIM	MIN	MAX	
Α	10.70	10.95	
В	7.70	7.90	
C	2.60	2.80	
D	0.66	0.86	
F	3.10	3.30	
G	4.48	4.68	
Н	2.00	2.20	
J	1.35	1.55	
K	15.30	16.30	
Q	3.70	3.90	
R	0.40	0.60	
V	1.17	1.37	



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA ; I _B = 0	100			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10uA; I _E = 0	120			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μ A; I _C = 0	6			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			0.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			1.2	V
Ісво	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			0.1	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			0.1	μ A
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	100		400	
h _{FE-2}	DC Current Gain	I _C = 1A; V _{CE} = 5V	30			
fτ	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 5V		100		MHz
Сов	Output Capacitance	I _E =0; V _{CB} = 10V, f _{test} = 1MHz		18		pF

♦ h_{FE} -1Classifications

Q	S	Ţ	
100-200	140-280	200-400	

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